



# TPD12S521 Single-Chip HDMI Transmitter Port Protection and Interface Device

## 1 Features

- IEC 61000-4-2 Level 4 ESD Protection
  - $\pm 8$ -kV Contact Discharge on External Lines
- Single-Chip ESD Solution for HDMI Driver
- On-Chip Current Regulator with 55-mA Current Output
- Supports All HDMI 1.3 and HDMI 1.4b Data Rates ( $-3$  dB Frequency  $> 3$  GHz)
- 0.8-pF Capacitance for the High Speed TMDS Lines
- 0.05-pF Matching Capacitance Between the Differential Signal Pair
- 38-Pin TSSOP Provides Seamless Layout Option with HDMI Connector
- Backdrive Protection
  - TMDS\_D[2:0]+/-
  - TMDS\_CK+/-
  - CE\_REMOTE\_OUT
  - DDC\_DAT\_OUT
  - DDC\_CLK\_OUT
  - HOTPLUG\_DET\_OUT
- Lead-Free Package

## 2 Applications

- PCs
- Consumer Electronics
- Set-Top Boxes
- DVD Players

## 4 Circuit Protection Scheme

## 3 Description

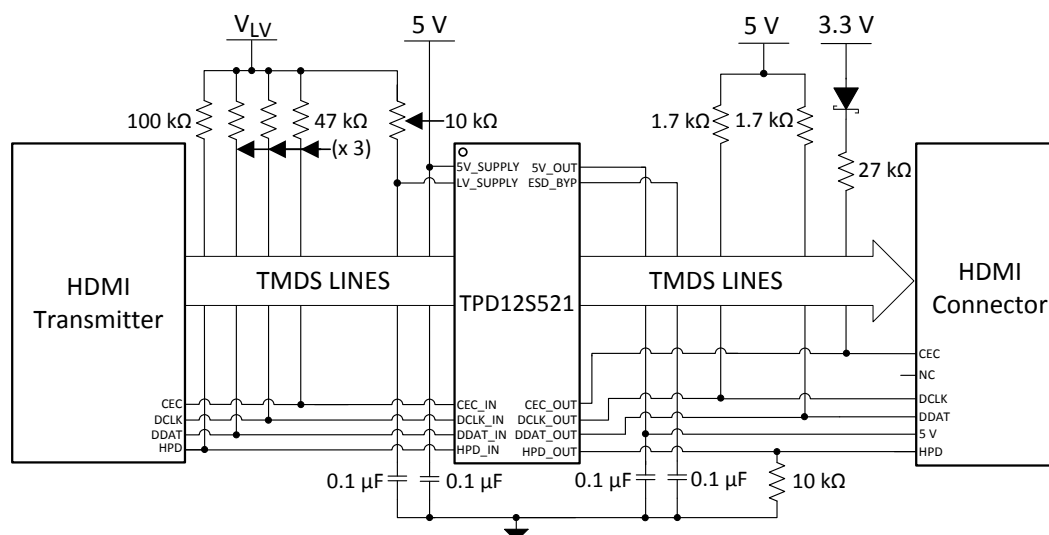
The TPD12S521 is a single-chip electro-static discharge (ESD) circuit protection device for the high-definition multimedia interface (HDMI) transmitter port. While providing ESD protection with transient voltage suppression (TVS) diodes, the TVS protection adds little or no additional glitch in the high-speed differential signals. The high-speed transition minimized differential signaling (TMDS) ESD protection lines add only 0.8-pF capacitance.

The low-speed control lines offer voltage-level shifting to eliminate the need for an external voltage level-shifter IC. The control line TVS diodes add 3.5-pF capacitance to the control lines. The 38-pin DBT package offers a seamless layout routing option to eliminate the routing glitch for the differential signal pairs. The DBT package pitch (0.5 mm) matches with the HDMI connector pitch. In addition, the pin mapping follows the same order as the HDMI connector pin mapping. The TPD12S521 provides an on-chip current limiting switch with output ratings of 55 mA at pin 38. This enables HDMI receiver detection even when the receiver device is powered off.

### Device Information<sup>(1)</sup>

| PART NUMBER | PACKAGE    | BODY SIZE (NOM)          |
|-------------|------------|--------------------------|
| TPD12S521   | TSSOP (38) | 6.40 mm $\times$ 9.70 mm |

(1) For all available packages, see the orderable addendum at the end of the datasheet.



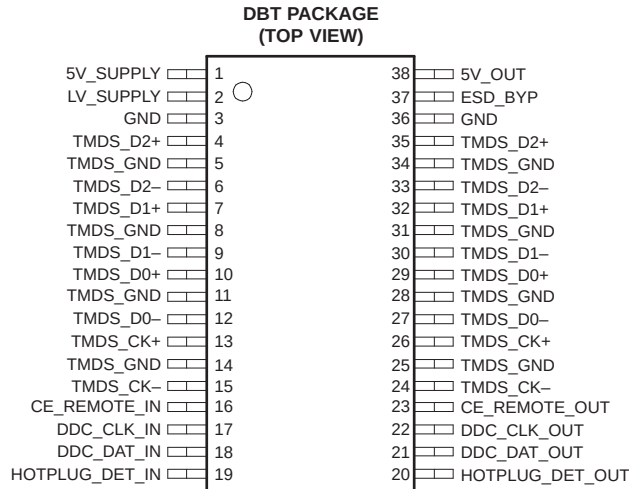
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## 5 Revision History

|                                                                                                                                                                                                                                                                                                 |             |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------|
| <b>Changes from Revision E (February 2015) to Revision F</b> .....                                                                                                                                                                                                                              | <b>Page</b> |
| • Add text to <a href="#">Typical Application</a> .....                                                                                                                                                                                                                                         | <b>1</b>    |
| <b>Changes from Revision D (September 2014) to Revision E</b> .....                                                                                                                                                                                                                             | <b>Page</b> |
| • Added clarification to HDMI data rates .....                                                                                                                                                                                                                                                  | <b>1</b>    |
| • Added clarification to HDMI data rates .....                                                                                                                                                                                                                                                  | <b>8</b>    |
| <b>Changes from Revision C (January 2013) to Revision D</b> .....                                                                                                                                                                                                                               | <b>Page</b> |
| • Added Handling Rating table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section ..... | <b>1</b>    |

## 6 Pin Configuration and Functions



### Pin Functions

| PIN             |                                     | TYPE          | ESD                 | DESCRIPTION                                                                         |
|-----------------|-------------------------------------|---------------|---------------------|-------------------------------------------------------------------------------------|
| NAME            | NO.                                 |               |                     |                                                                                     |
| 5V_SUPPLY       | 1                                   | PWR           | 2 kV <sup>(1)</sup> | Current source for 5V_OUT.                                                          |
| LV_SUPPLY       | 2                                   |               |                     | Bias for CE/DDC/HOTPLUG level shifters.                                             |
| GND, TMDS_GND   | 3, 5, 8, 11, 14, 25, 28, 31, 34, 36 | GND           | NA                  | TMDS ESD and parasitic GND return.                                                  |
| TMDS_D2+        | 4, 35                               | ESD clamp     | 8 kV <sup>(2)</sup> | TMDS 0.8-pF ESD protection. <sup>(3)</sup>                                          |
| TMDS_D2-        | 6, 33                               |               |                     |                                                                                     |
| TMDS_D1+        | 7, 32                               |               |                     |                                                                                     |
| TMDS_D1-        | 9, 30                               |               |                     |                                                                                     |
| TMDS_D0+        | 10, 29                              |               |                     |                                                                                     |
| TMDS_D0-        | 12, 27                              |               |                     |                                                                                     |
| TMDS_CK+        | 13, 26                              |               |                     |                                                                                     |
| TMDS_CK-        | 15, 24                              |               |                     |                                                                                     |
| CE_REMOTE_IN    | 16                                  | IO            | 2 kV <sup>(1)</sup> | LV_SUPPLY referenced logic level into ASIC.                                         |
| DDC_CLK_IN      | 17                                  |               |                     |                                                                                     |
| DDC_DAT_IN      | 18                                  |               |                     |                                                                                     |
| HOTPLUG_DET_IN  | 19                                  |               |                     |                                                                                     |
| HOTPLUG_DET_OUT | 20                                  | IO, ESD clamp | 8 kV <sup>(2)</sup> | 5 V_SUPPLY referenced logic level out, plus 3.5-pF ESD <sup>(4)</sup> to connector. |
| DDC_DAT_OUT     | 21                                  |               |                     | 5 V_SUPPLY referenced logic level out, plus 3.5-pF ESD to connector.                |
| DDC_CLK_OUT     | 22                                  |               |                     | 3.3-V_SUPPLY referenced logic level out, plus 3.5-pF ESD to connector.              |
| CE_REMOTE_OUT   | 23                                  | IO, ESD clamp | 8 kV <sup>(2)</sup> | 3.3-V_SUPPLY referenced logic level out, plus 3.5-pF ESD to connector.              |
| ESD_BYP         | 37                                  | ESD Bypass    | 2 kV <sup>(1)</sup> | ESD bypass. This pin must be connected to a 0.1-μF ceramic capacitor.               |
| 5V_OUT          | 38                                  | PWR           | 2 kV <sup>(1)</sup> | 5-V regulator output                                                                |

(1) Human-Body Model (HBM) per MIL-STD-883, Method 3015, C<sub>DISCHARGE</sub> = 100 pF, R<sub>DISCHARGE</sub> = 1.5 kΩ, 5V\_SUPPLY and LV\_SUPPLY within recommended operating conditions, GND = 0 V, and ESD\_BYP (pin 37) and HOTPLUG\_DET\_OUT (pin 20) each bypassed with a 0.1-μF ceramic capacitor connected to GND.

(2) Standard IEC 61000-4-2, C<sub>DISCHARGE</sub> = 150 pF, R<sub>DISCHARGE</sub> = 330 Ω, 5V\_SUPPLY and LV\_SUPPLY within recommended operating conditions, GND = 0 V, and ESD\_BYP (pin 37) and HOTPLUG\_DET\_OUT (pin 20) each bypassed with a 0.1-μF ceramic capacitor connected to GND.

(3) These two pins must be connected together inline on the PCB.

(4) This output can be connected to an external 0.1-μF ceramic capacitor, resulting in an increased ESD withstand voltage rating.

## 7 Specifications

### 7.1 Absolute Maximum Ratings<sup>(1)(2)</sup>

over operating free-air temperature range (unless otherwise noted)

|                        |                                 | MIN  | MAX | UNIT |
|------------------------|---------------------------------|------|-----|------|
| V <sub>5V_SUPPLY</sub> | Supply voltage                  | −0.3 | 6   | V    |
| V <sub>LV_SUPPLY</sub> |                                 |      |     |      |
| V <sub>I/O</sub>       | DC voltage at any channel input | −0.5 | 6   | V    |
| T <sub>stg</sub>       | Storage temperature range       | −65  | 150 | °C   |

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

### 7.2 ESD Ratings

|                    |                         |                                                                                                                                       | VALUE | UNIT |
|--------------------|-------------------------|---------------------------------------------------------------------------------------------------------------------------------------|-------|------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per MIL-STD-883, Method 3015, C <sub>DISCHARGE</sub> = 100 pF, R <sub>DISCHARGE</sub> = 1.5 kΩ <sup>(1)</sup> | ±2000 | V    |
|                    |                         | IEC 61000-4-2 Contact Discharge <sup>(2)</sup>                                                                                        | ±8000 |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.

### 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                |                                | MIN | TYP | MAX | UNIT |
|----------------|--------------------------------|-----|-----|-----|------|
| T <sub>A</sub> | Operating free-air temperature | −40 |     | 85  | °C   |
| 5V_SUPPLY      | Operating supply voltage       |     | 5   | 5.5 | V    |
| LV_SUPPLY      | Bias supply voltage            | 1   | 3.3 | 5.5 | V    |

### 7.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | TPD12S521 | UNIT |
|-------------------------------|----------------------------------------------|-----------|------|
|                               |                                              | DBT       |      |
|                               |                                              | 38 PINS   |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 83.6      | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 29.8      |      |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 44.7      |      |
| Ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 2.9       |      |
| Ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 44.1      |      |

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

## 7.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

| PARAMETER               |                                                                        | TEST CONDITIONS                                                                                                                       | MIN                 | TYP  | MAX  | UNIT |
|-------------------------|------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------|---------------------|------|------|------|
| I <sub>CC5</sub>        | Operating supply current                                               | 5V_SUPPLY = 5 V                                                                                                                       |                     | 110  | 130  | μA   |
| I <sub>CC3</sub>        | Bias supply current                                                    | LV_SUPPLY = 3.3 V                                                                                                                     |                     | 1    | 5    | μA   |
| V <sub>DROP</sub>       | 5V_OUT overcurrent output drop                                         | 5V_SUPPLY = 5 V, I <sub>OUT</sub> = 55 mA                                                                                             |                     | 150  | 200  | mV   |
| I <sub>SC</sub>         | 5V_OUT short-circuit current limit                                     | 5V_SUPPLY = 5 V, 5V_OUT = GND                                                                                                         | 90                  | 135  | 175  | mA   |
| I <sub>OFF</sub>        | OFF-state leakage current, level-shifting NFET                         | LV_SUPPLY = 0 V                                                                                                                       |                     | 0.1  | 5    | μA   |
| I <sub>BACK DRIVE</sub> | Current conducted from output pins to V_SUPPLY rails when powered down | 5V_SUPPLY < V <sub>CH_OUT</sub><br>TMDS_D[2:0]+/–,<br>TMDS_CK+/,<br>CE_REMOTE_OUT,<br>DDC_DAT_OUT,<br>DDC_CLK_OUT,<br>HOTPLUG_DET_OUT |                     | 0.1  | 5    | μA   |
| V <sub>ON</sub>         | Voltage drop across level-shifting NFET when ON                        | LV_SUPPLY = 2.5 V, V <sub>S</sub> = GND, I <sub>DS</sub> = 3 mA                                                                       | 75                  | 95   | 140  | mV   |
| V <sub>F</sub>          | Diode forward voltage                                                  | I <sub>F</sub> = 8 mA,<br>T <sub>A</sub> = 25°C <sup>(1)</sup>                                                                        | Top diode           |      | 0.85 | V    |
|                         |                                                                        |                                                                                                                                       | Bottom diode        |      | 0.85 |      |
| V <sub>CL</sub>         | Channel clamp voltage at ±8 kV HBM ESD                                 | T <sub>A</sub> = 25°C <sup>(1)(2)</sup>                                                                                               | Positive transients |      | 9    | V    |
|                         |                                                                        |                                                                                                                                       | Negative transients |      | –9   |      |
| R <sub>DYN</sub>        | Dynamic resistance                                                     | I = 1 A, T <sub>A</sub> = 25°C <sup>(3)</sup>                                                                                         | Positive transients |      | 3    | Ω    |
|                         |                                                                        |                                                                                                                                       | Negative transients |      | 1.5  |      |
| I <sub>LEAK</sub>       | TMDS channel leakage current                                           | T <sub>A</sub> = 25°C <sup>(1)</sup>                                                                                                  |                     | 0.01 | 1    | μA   |
| C <sub>IN, TMDS</sub>   | TMDS channel input capacitance                                         | 5V_SUPPLY = 5 V, Measured at 1 MHz,<br>V <sub>BIAS</sub> = 2.5 V <sup>(1)</sup>                                                       |                     | 0.8  | 1.0  | pF   |
| ΔC <sub>IN, TMDS</sub>  | TMDS channel input capacitance matching                                | 5V_SUPPLY = 5 V, Measured at 1 MHz,<br>V <sub>BIAS</sub> = 2.5 V <sup>(1)(4)</sup>                                                    |                     | 0.05 |      | pF   |
| C <sub>MUTUAL</sub>     | Mutual capacitance between signal pin and adjacent signal pin          | 5V_SUPPLY = 0 V, Measured at 1 MHz,<br>V <sub>BIAS</sub> = 2.5 V <sup>(1)</sup>                                                       |                     | 0.07 |      | pF   |
| C <sub>IN</sub>         | Level-shifting input capacitance, capacitance to GND                   | 5V_SUPPLY = 0 V, Measured at 100 KHz,<br>V <sub>BIAS</sub> = 2.5 V <sup>(1)</sup>                                                     | DDC                 | 3.5  | 4    | pF   |
|                         |                                                                        |                                                                                                                                       | CEC                 | 3.5  | 4    |      |
|                         |                                                                        |                                                                                                                                       | HP                  | 3.5  | 4    |      |

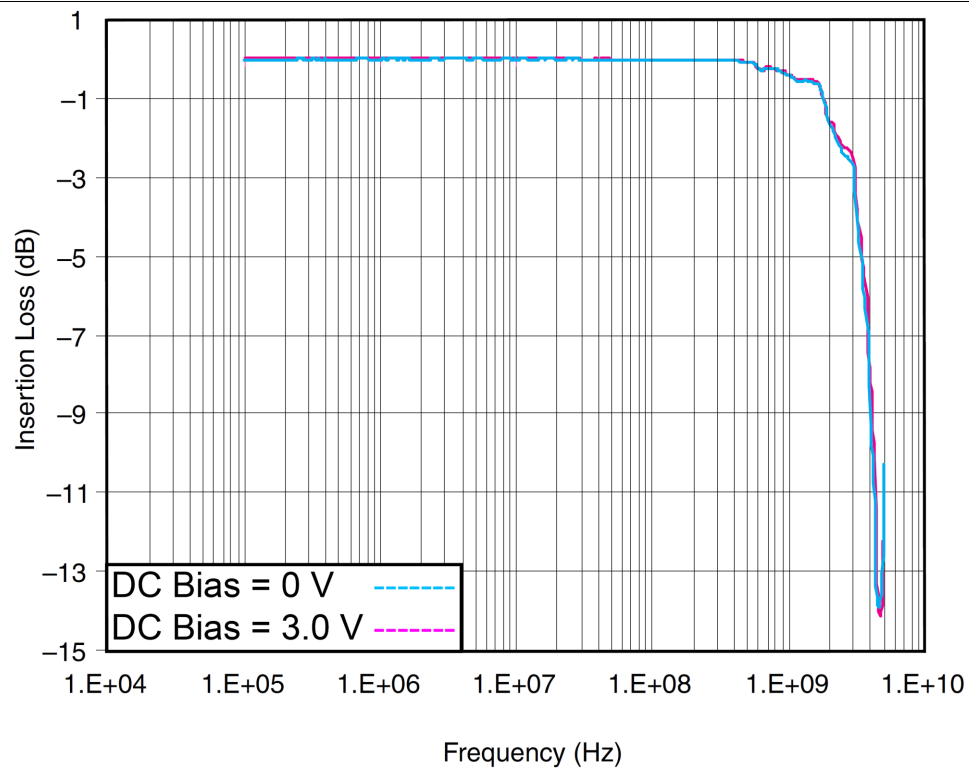
(1) This parameter is specified by design and verified by device characterization

(2) Human-Body Model (HBM) per MIL-STD-883, Method 3015, C<sub>DISCHARGE</sub> = 100 pF, R<sub>DISCHARGE</sub> = 1.5 kΩ

(3) These measurements performed with no external capacitor on ESD\_BYP.

(4) Intrapair matching, each TMDS pair (i.e., D+, D–)

## 7.6 Typical Characteristics



**Figure 1. Insertion Loss Performance Across Frequency**

## 8 Detailed Description

### 8.1 Overview

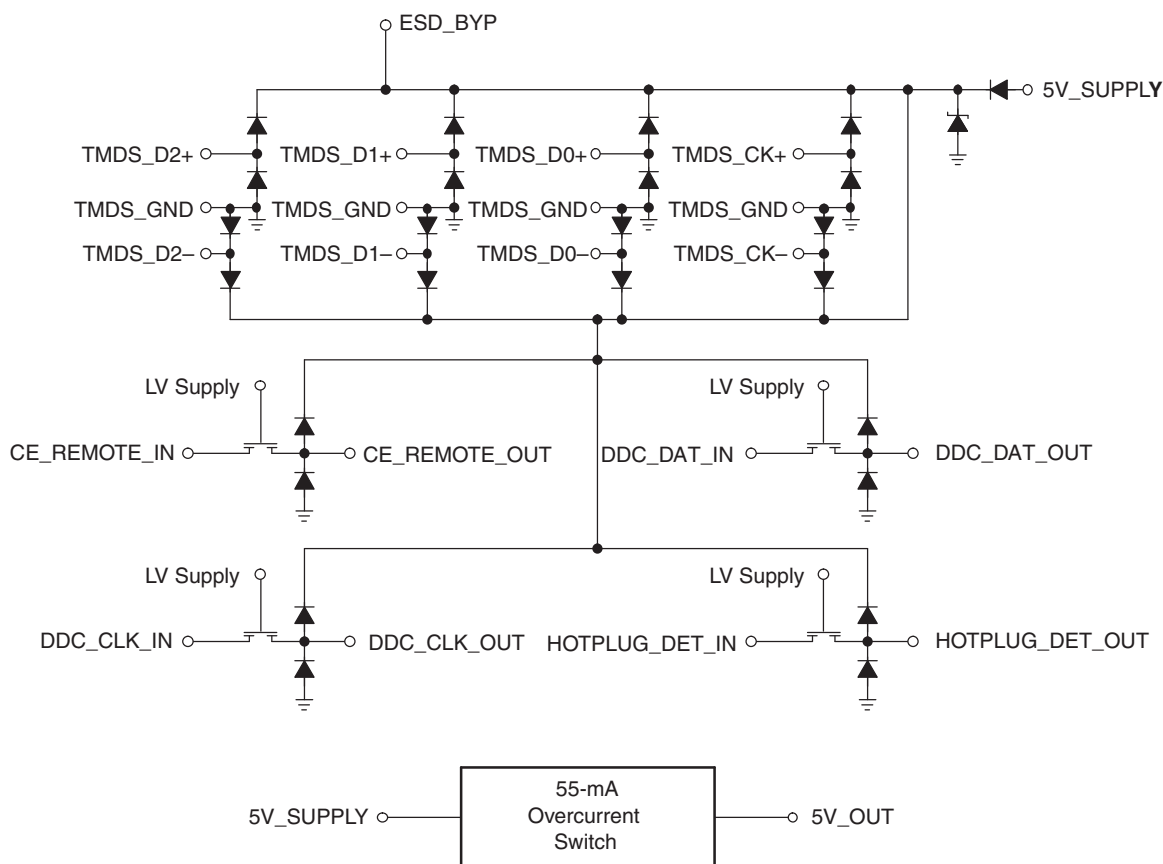
The TPD12S521 is a single-chip ESD solution for the HDMI transmitter port. In many cases the core ICs, such as the scalar chipset, may not have robust ESD cells to sustain system-level ESD strikes. In these cases, the TPD12S521 provides the desired system-level ESD protection, such as the IEC61000-4-2 (Level 4) ESD, by absorbing the energy associated with the ESD strike.

While providing the ESD protection, the TPD12S521 adds little or no additional glitch in the high-speed differential signals (see Figure 5 and Figure 6). The high-speed TMDS lines add only 0.8-pF capacitance to the lines. In addition, the monolithic integrated circuit technology ensures that there is excellent matching between the two-signal pair of the differential line. This is a direct advantage over discrete ESD clamp solutions where variations between two different ESD clamps may significantly degrade the differential signal quality.

The low-speed control lines offer voltage-level shifting to eliminate the need for an external voltage level-shifter IC. The control line ESD clamps add 3.5-pF capacitance to the control lines. The 38-pin DBT package offers a seamless layout routing option to eliminate the routing glitch for the differential signal pairs.

The TPD12S521 provides an on-chip regulator with current output ratings of 55 mA at pin 38. This current enables HDMI receiver detection even when the receiver device is powered off. DBT package pitch (0.5 mm) matches with HDMI connector pitch. In addition, pin mapping follows the same order as the HDMI connector pin mapping.

### 8.2 Functional Block Diagram



## 8.3 Feature Description

### 8.3.1 Single-Chip ESD Solution for HDMI Driver

TPD12S521 provides a complete ESD protection scheme for an HDMI 1.4 compliant port. The monolithic integrated circuit technology ensures that there is excellent matching between the two-signal pair of the differential line. This is a direct advantage over discrete ESD clamp solutions where variations between two different ESD clamps may significantly degrade the differential signal quality. The 38-pin DBT package offers a seamless layout routing option to eliminate the routing glitch for the differential signal pair.

### 8.3.2 Supports All HDMI 1.3 and HDMI 1.4b Data Rates

The high-speed TMDS pins of the TPD12S521 add only 0.8 pF of capacitance to the TMDS lines. Excellent intra-pair capacitance matching of 0.05 pF provides ultra low intra-pair skew. Insertion loss -3 dB point > 3 GHz provides enough bandwidth to pass all HDMI 1.4b TMDS data rates.

### 8.3.3 Integrated Level Shifting for the Control Lines

The low-speed control lines offer voltage-level shifting to eliminate the need for an external voltage level-shifter IC. The control line ESD clamps add 3.5-pF capacitance to the control lines.

### 8.3.4 ±8-kV Contact ESD Protection on External Lines

In many cases, the core ICs, such as the scalar chipset, may not have robust ESD cells to sustain system-level ESD strikes. In these cases, the TPD12S521 provides the desired system-level ESD protection, such as the IEC61000-4-2 (Level 4) ESD, by absorbing the energy associated with the ESD strike.

### 8.3.5 38-Pin TSSOP Provides Seamless Layout Option With HDMI Connector

The 38-pin DBT package offers seamless layout routing option to eliminate the routing glitch for the differential signal pair. DBT package pitch (0.5 mm) matches with HDMI connector pitch. In addition, pin mapping follows the same order as the HDMI connector pin mapping. This HDMI receiver port protection and interface device is specifically designed for next-generation HDMI transmitter protection.

### 8.3.6 Backdrive Protection

Backdrive protection is offered on the following pins: TMDS\_D[2:0]+/–, TMDS\_CK+/–, CE\_REMOTE\_OUT, DDC\_DAT\_OUT, DDC\_CLK\_OUT, HOTPLUG\_DET\_OUT.

### 8.3.7 Lead-Free Package

Lead-Free Package for RoHS Compliance.

### 8.3.8 On-Chip Current Regulator With 55-mA Current Output

The TPD12S521 provides an on-chip regulator with current output ratings of 55 mA at pin 38. This current enables HDMI receiver detection even when the receiver device is powered off.

## 8.4 Device Functional Modes

TPD12S521 is active with the conditions in the [Recommended Operating Conditions](#) met. The bi-directional voltage-level translators provide non-inverting level shifting from  $V_{LV}$  on the system side to either 5V (for SDA, SCL, HPD), or 3.3 V (for CEC) on the connector side. Each connector side pin has an ESD clamp that triggers when voltages are above  $V_{BR}$  or below the lower diode's  $V_f$ . During ESD events, voltages as high as ±8-kV (contact ESD) can be directed to ground via the internal diode network. Once the voltages on the protected line fall below these trigger levels (usually within 10's of nano-seconds), these pins revert to a non-conductive state.

## 9 Application and Implementation

### NOTE

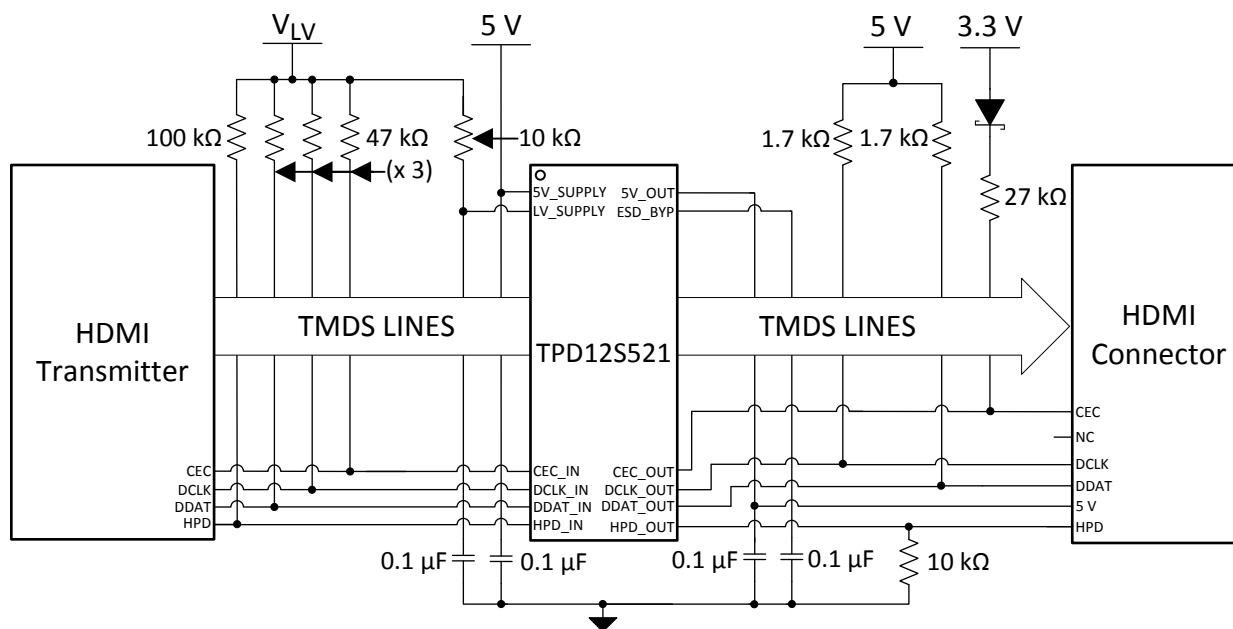
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

TPD12S521 provides IEC61000-4-2 Level 4 Contact ESD rating to the HDMI 1.4 transmitter port. Integrated voltage-level shifting reduces the board space needed to implement the control lines.

### 9.2 Typical Application

Refer to [Figure 2](#) for a typical schematic for an HDMI 1.4 transmitter port protected with TPD12S521. The eight TMDS data lines (D2+/-, D1+/-, D0+/-, CLK+/-) each have two pins on TPD12S521 to connect to. The TMDS data lines flow through their respective pin pairs, attaching to the passive ESD protection circuitry. To block reverse current to the 3.3-V logic power rail, connect CEC\_OUT to the 3.3-V logic level with a 27-k $\Omega$  pull-up resistor in series with a Schottky diode.



**Figure 2. TPD12S521 Configured With an HDMI 1.4 Transmitter Port**

#### 9.2.1 Design Requirements

For this example, use the following table as input parameters:

| Design Parameters    | Example Value |
|----------------------|---------------|
| Voltage on 5V_SUPPLY | 4.5 V - 5.5 V |
| Voltage on LV_SUPPLY | 1.7 V - 1.9 V |

## 9.2.2 Detailed Design Procedure

To begin the design process the designer needs to know the 5V\_SUPPLY voltage range and the logic level, LV\_SUPPLY, voltage range.

## 9.2.3 Application Curves

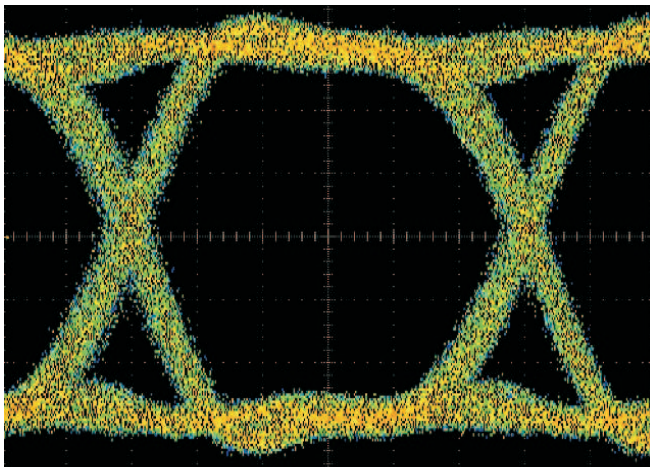


Figure 3. HDMI 1.65Gbps Eye Diagram With TPD12S521 on a Test Board

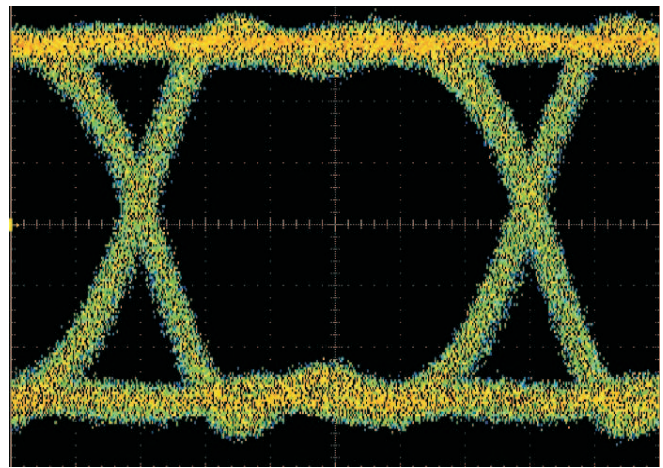


Figure 4. HDMI 1.65Gbps Eye Diagram Without TPD12S521 on a Test Board

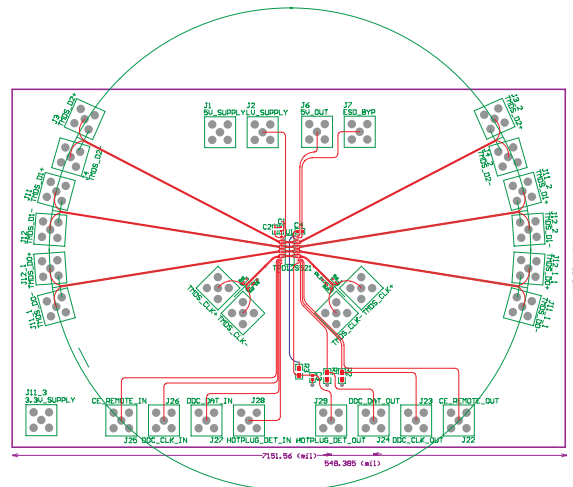


Figure 5. Test Board to Measure Eye Diagram for the TPD12S521 (Refer to Eye Diagram Plot)

## 10 Power Supply Recommendations

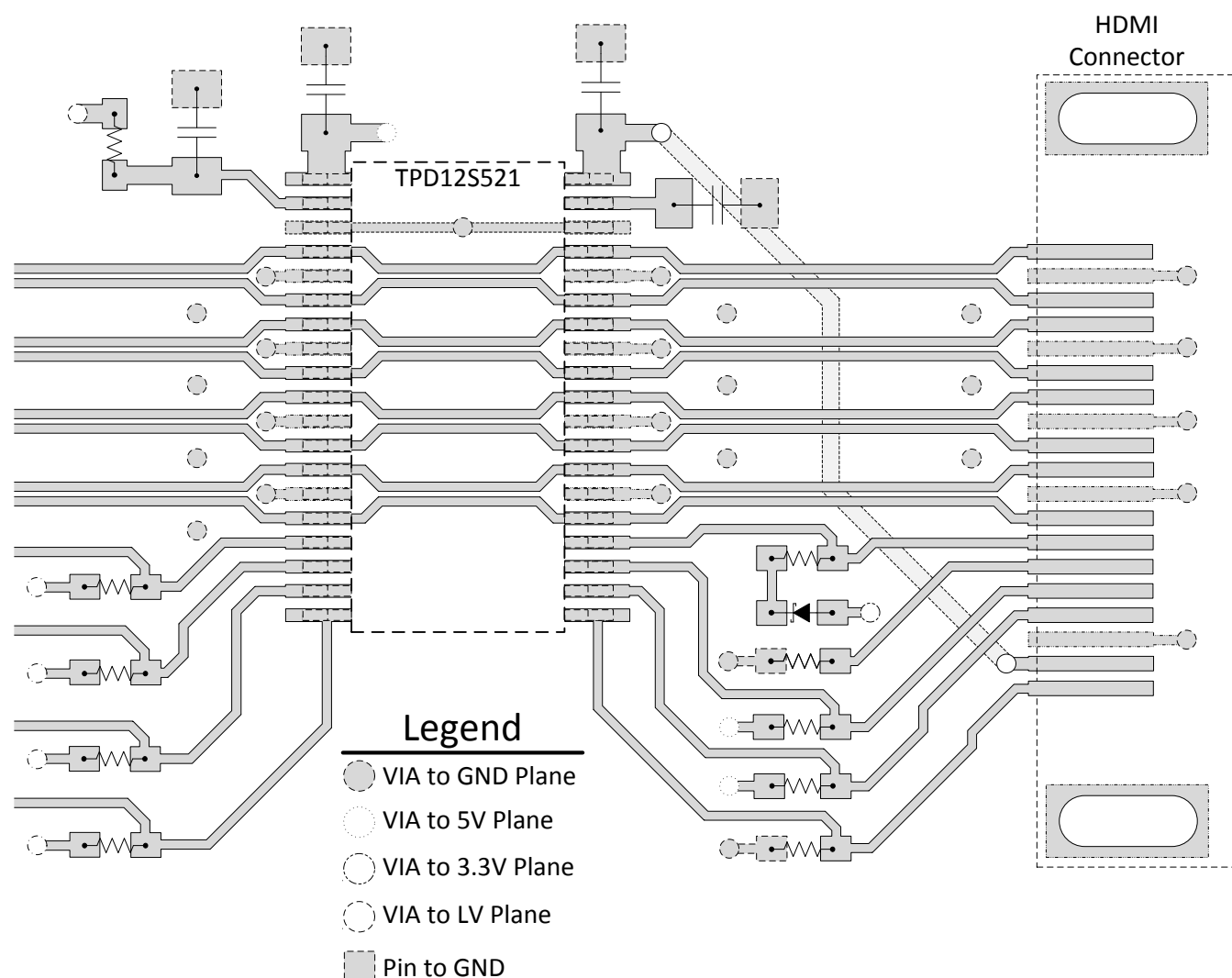
The designer needs to consider the requirement for the HDMI Transmitters Hot Plug Detect (HPD) scheme. If it is a requirement, then the  $V_{IH}$  of HPD on the core scalar chip is the minimum voltage needed to detect a Hot Plug event. The minimum voltage requirement is  $V_{5V\_SUPPLY} - V_{DROP\_MAX} - V_{DROP\_SYSTEM} - V_{ON\_MAX} > V_{IH} \Rightarrow V_{5V\_SUPPLY} > V_{IH} + V_{DROP\_MAX} + V_{DROP\_SYSTEM} + V_{ON\_MAX}$ ; where  $V_{DROP\_MAX}$  is the maximum voltage drop across TPD12S521's current limiter,  $V_{DROP\_SYSTEM}$  is the voltage drop across the path from Pin 38 of TPD12S521 through the sink and back to Pin 20, and  $V_{ON\_MAX}$  is the maximum voltage drop across TPD12S521's level shifting NFET when ON. Otherwise, TPD12S521 is a passive ESD protection device and there is no need to power it.

## 11 Layout

### 11.1 Layout Guidelines

- The optimum placement is as close to the connector as possible.
  - EMI during an ESD event can couple from the trace being struck to other nearby unprotected traces, resulting in early system failures.
  - The PCB designer needs to minimize the possibility of EMI coupling by keeping any unprotected traces away from the protected traces which are between the TVS and the connector.
- Route the protected traces as straight as possible.
- Eliminate any sharp corners on the protected traces between the TVS and the connector by using rounded corners with the largest radii possible.
  - Electric fields tend to build up on corners, increasing EMI coupling.

### 11.2 Layout Example



Use external and internal ground planes and stitch them together with VIAs as close to the GND pins of TPD12S521 as possible. This allows for a low impedance path to ground so that the device can properly dissipate an ESD event.

## 12 Device and Documentation Support

### 12.1 Trademarks

All trademarks are the property of their respective owners.

### 12.2 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 12.3 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable part number | Status<br>(1) | Material type<br>(2) | Package   Pins   | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-----------------------|---------------|----------------------|------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| TPD12S521DBTR         | Active        | Production           | TSSOP (DBT)   38 | 2000   LARGE T&R      | Yes         | NIPDAU   NIPDAU                      | Level-2-260C-1 YEAR               | -40 to 85    | PN521               |
| TPD12S521DBTR.B       | Active        | Production           | TSSOP (DBT)   38 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | PN521               |
| TPD12S521DBTRG4       | Active        | Production           | TSSOP (DBT)   38 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | PN521               |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

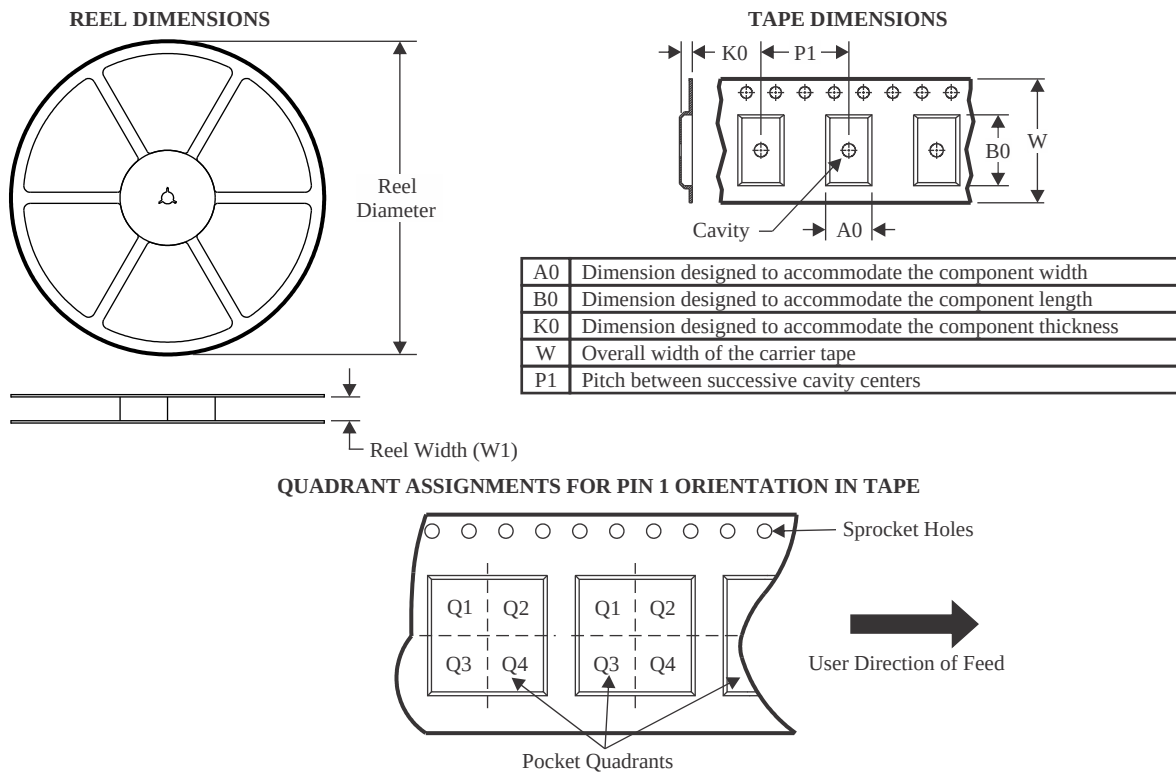
<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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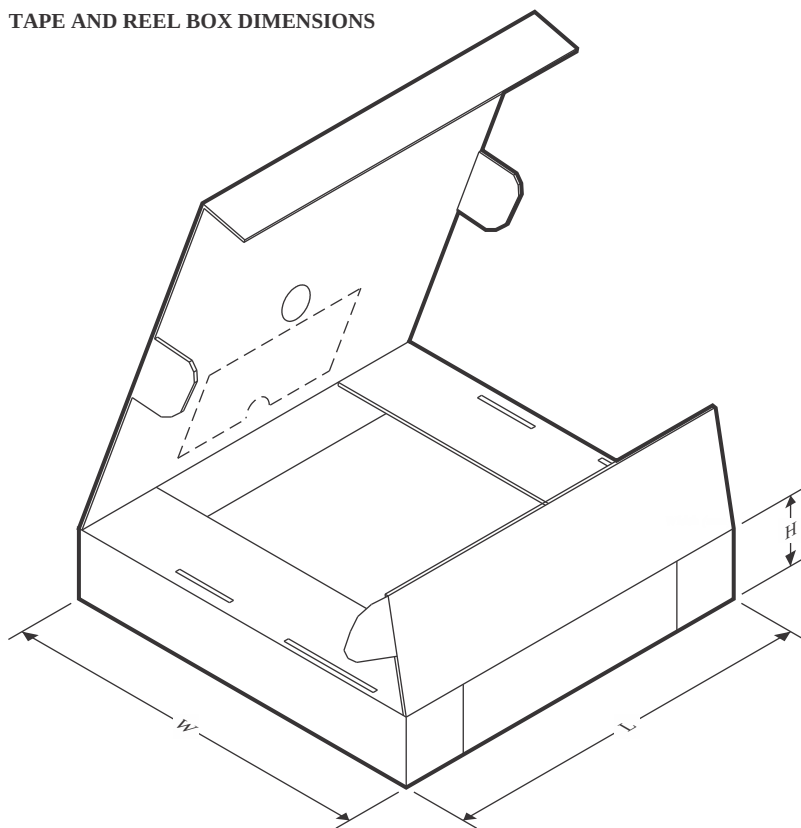
## TAPE AND REEL INFORMATION



\*All dimensions are nominal

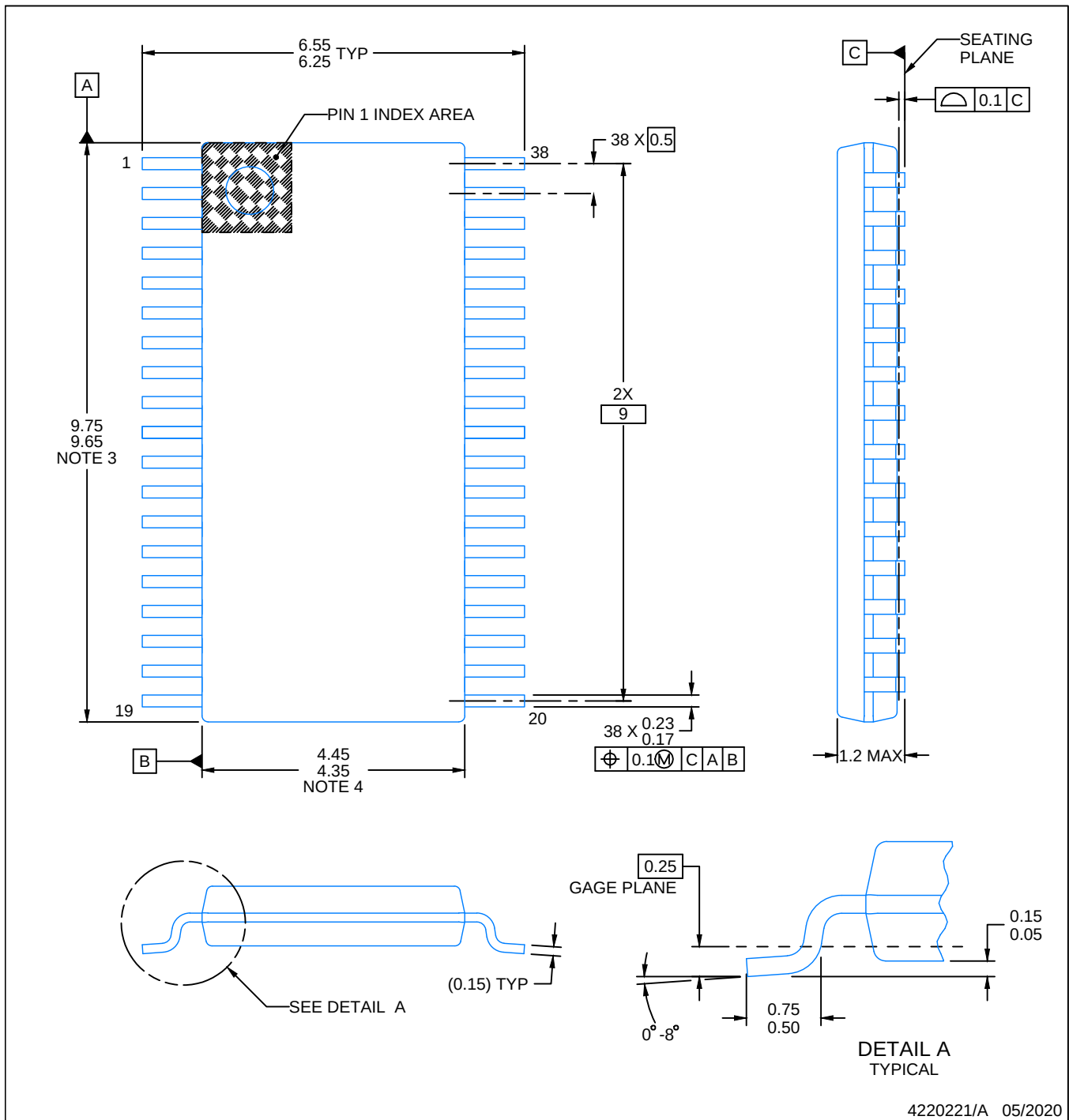
| Device        | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPD12S521DBTR | TSSOP        | DBT             | 38   | 2000 | 330.0              | 16.4               | 6.75    | 10.1    | 1.8     | 12.0    | 16.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

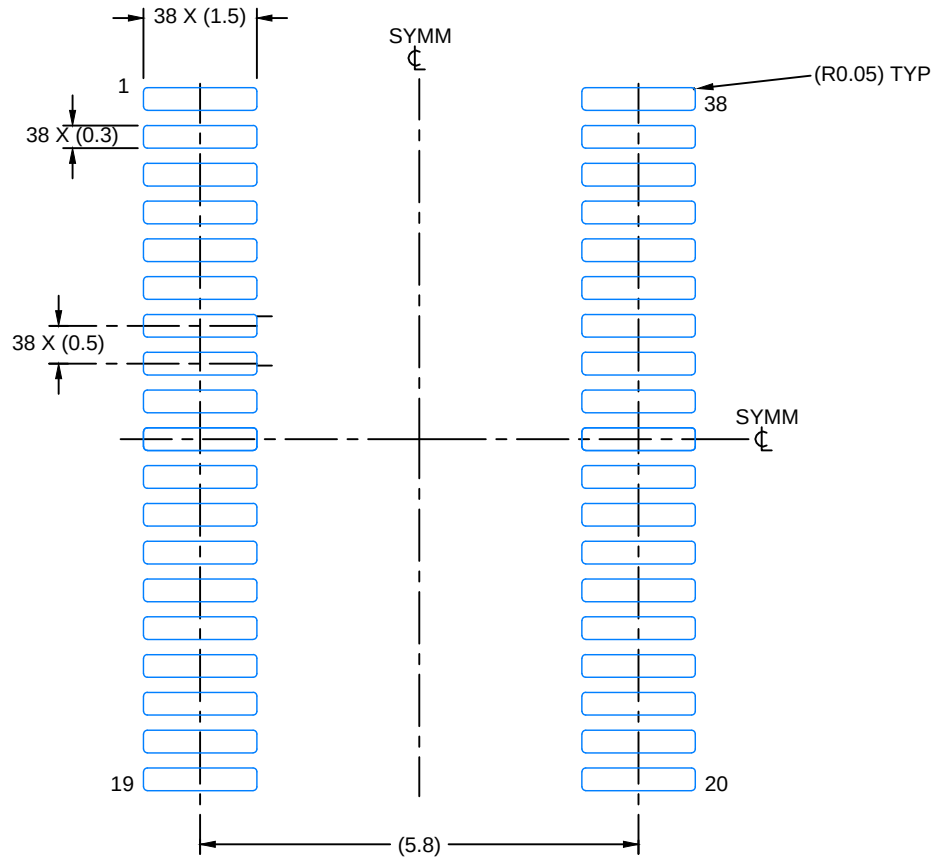
| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPD12S521DBTR | TSSOP        | DBT             | 38   | 2000 | 367.0       | 367.0      | 38.0        |



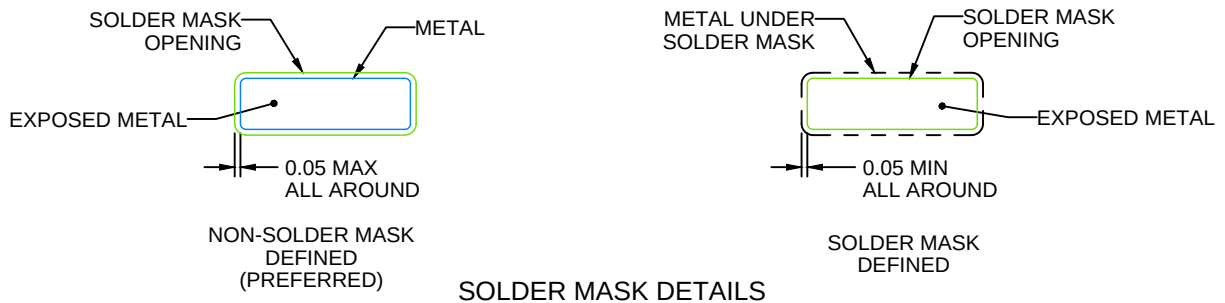
4220221/A 05/2020

#### NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X

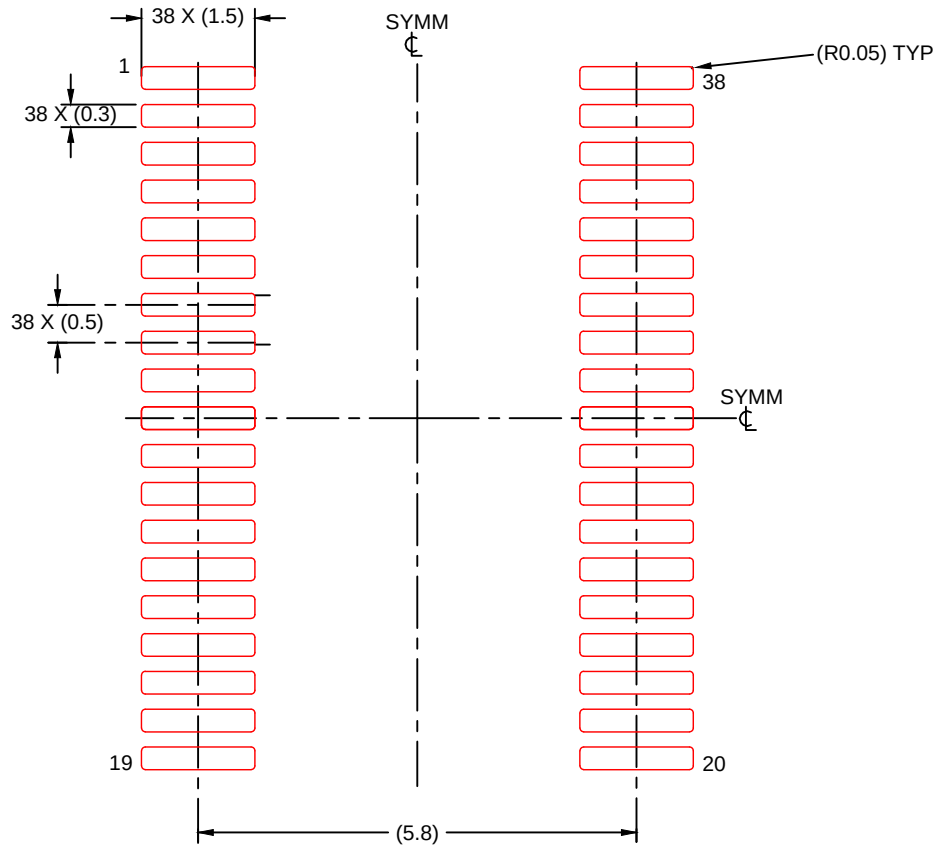


SOLDER MASK DETAILS

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE  
 BASED ON 0.125 mm THICK STENCIL  
 SCALE: 10X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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